

B5817WS-FL / B5818WS-FL / B5819WS-FL**List**

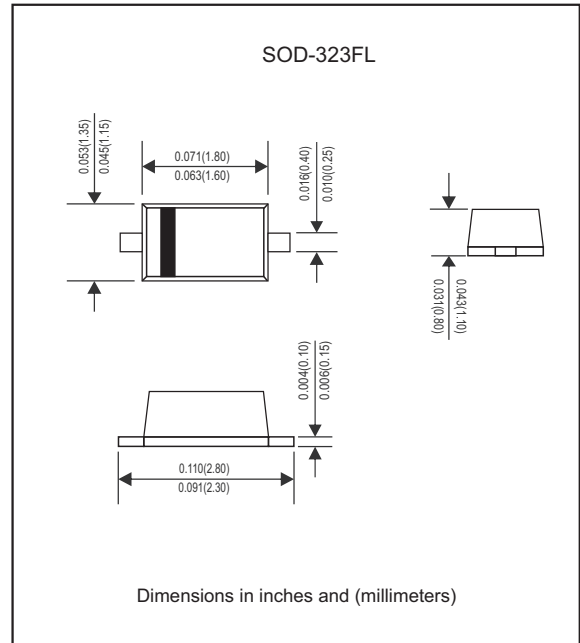
List.....	1
Package outline.....	2
Features.....	2
Mechanical data.....	2
Maximum ratings and Electrical characteristics	2
Rating and characteristic curves.....	3
Pinning information.....	4
Marking.....	4
Suggested solder pad layout.....	4
Packing information.....	5
Reel packing.....	6
Suggested thermal profiles for soldering processes.....	6
High reliability test capabilities.....	7

B5817WS-FL / B5818WS-FL / B5819WS-FL**1.0A Surface Mount Schottky
Barrier Diode 20V-40V****Features**

- Surface mounting type
- For use in low voltage, high frequency inverters
- Free wheeling, and polarity protection applications
- Lead-free parts meet RoHS requirements
- Suffix "-H" indicates Halogen-free parts, ex. B5817WS-FL-H

Mechanical data

- Epoxy:UL94-V0 rated flame retardant
- Case : Molded plastic, SOD-323FL
- Terminals : Solder plated, solderable per MIL-STD-750, Method 2026
- Polarity : Indicated by cathode band
- Mounting Position : Any
- Weight : Approximated 0.005 gram

Package Outline**Maximum ratings** (AT TA=25°C unless otherwise noted)

Parameter	Symbol	B5817WS-FL	B5818WS-FL	B5819WS-FL	Unit
Reverse voltage	V _R	20	30	40	V
Average forward rectified current	I _{F(AV)}	1			A
Non-repetitive peak forward surge current (t=8.3ms)	I _{FSM}	9			A
Power dissipation	P _{tot}	450			mW
Operating junction temperature range	T _J	-55 to +125			°C
Storage temperature range	T _{STG}	-55 to +125			°C

Electrical characteristics (AT TA=25°C unless otherwise noted)

Parameter	Symbol	B5817WS-FL	B5818WS-FL	B5819WS-FL	Unit
Minimum reverse breakdown voltage at I _R =1mA	V _{BR}	20	30	40	V
Maximum forward voltage at I _F =1A	V _F	0.45	0.55	0.60	V
Maximum forward voltage at I _F =3A		0.75	0.875	0.90	
Maximum reverse voltage leakage current at rated V _R	I _R	1			mA
Maximum total capacitance at V _R =4V, f=1MHz	C _{tot}	120			pF

Rating and characteristic curves (B5817WS-FL/B5818WS-FL/B5819WS-FL)

Fig.1 Forward Current Derating Curve

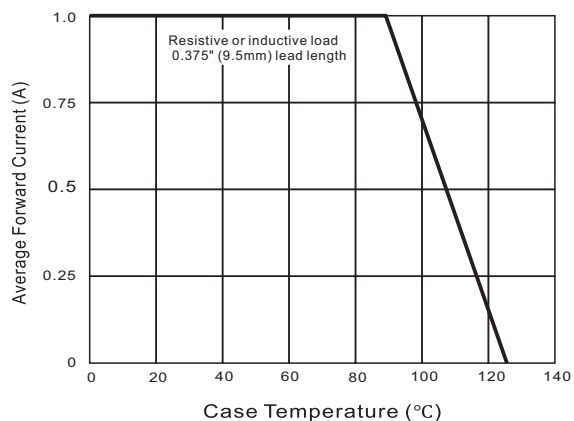


Fig.2 Maximum Non-Repetitive Peak Forward Surge Current

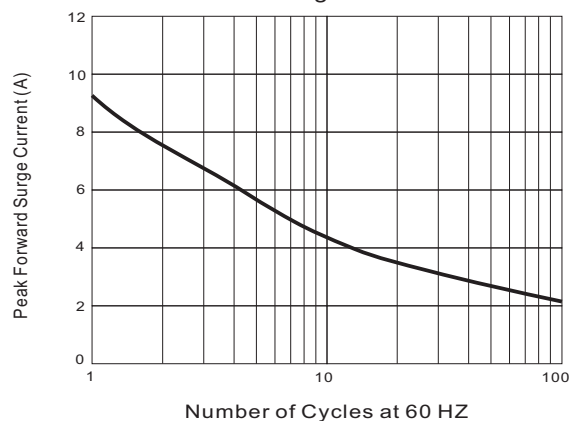


Fig.3 Typical Instantaneous Forward Characteristics

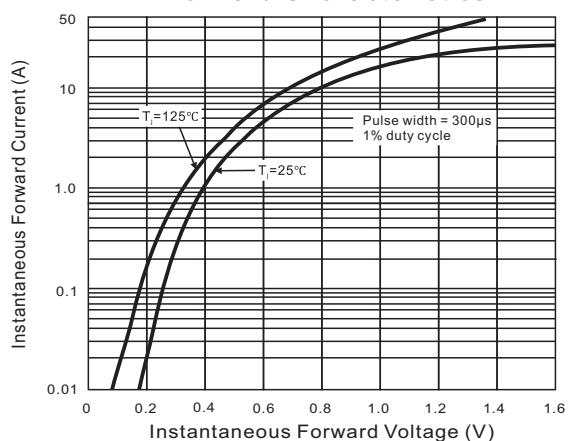


Fig.4 Typical Reverse Characteristics

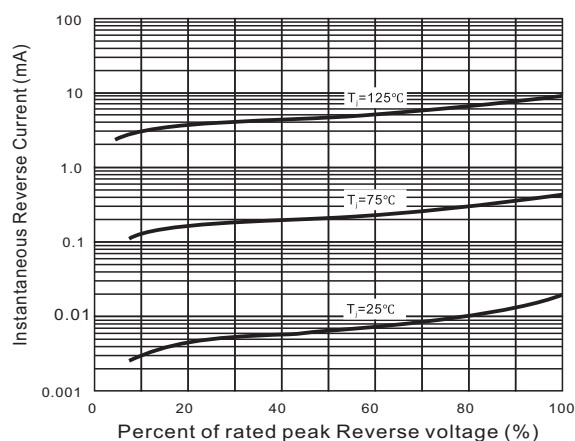


Fig.5 Typical Junction Capacitance

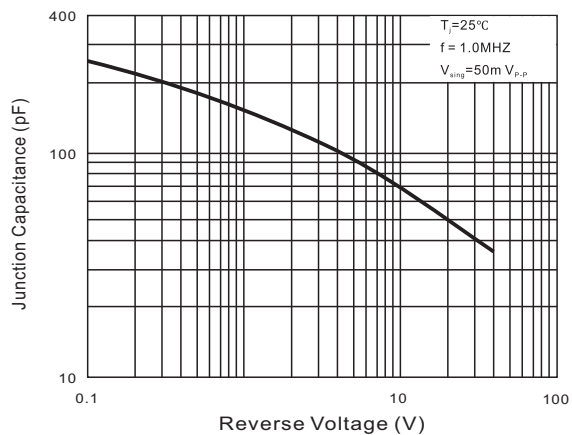
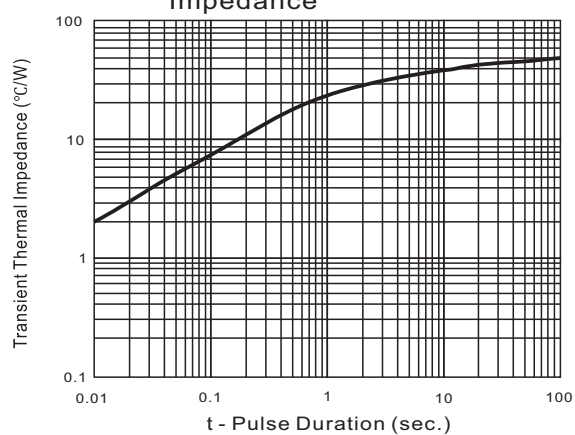


Fig.6 Typical Transient Thermal Impedance

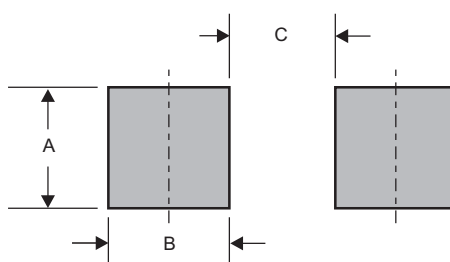


B5817WS-FL / B5818WS-FL / B5819WS-FL**Pinning information**

Pin	Simplified outline	Symbol
Pin1 cathode Pin2 anode		

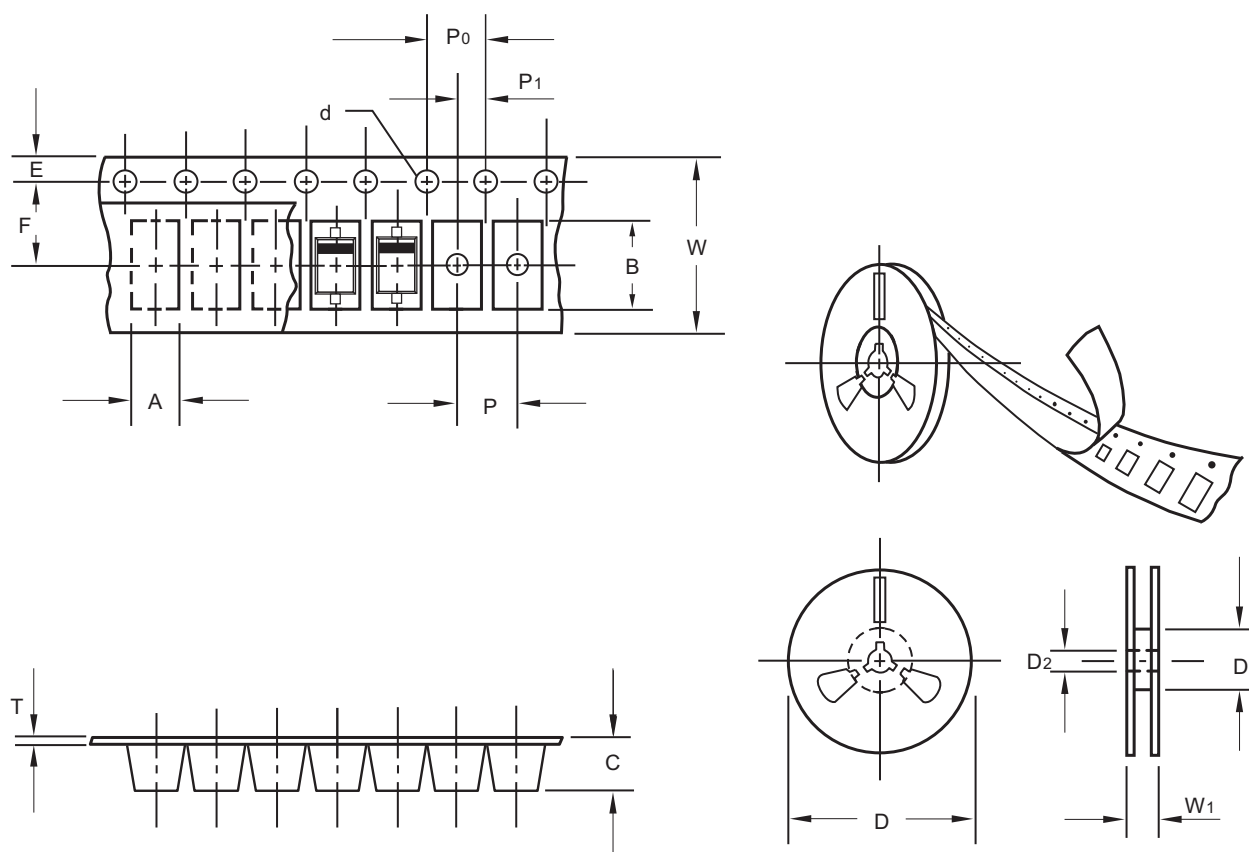
Marking

Type number	Marking code
B5817WS-FL	SJ
B5818WS-FL	SL
B5819WS-FL	SL

Suggested solder pad layout

Dimensions in inches and (millimeters)

PACKAGE	A	B	C
SOD-323FL	0.033 (0.83)	0.027 (0.70)	0.057 (1.45)

B5817WS-FL / B5818WS-FL / B5819WS-FL**Packing information**

unit:mm

Item	Symbol	Tolerance	SOD-323FL
Carrier width	A	0.1	1.45
Carrier length	B	0.1	2.75
Carrier depth	C	0.1	0.97
Sprocket hole	d	0.1	1.55
13" Reel outside diameter	D	2.0	-
13" Reel inner diameter	D1	min	-
7" Reel outside diameter	D	2.0	178.00
7" Reel inner diameter	D1	min	62.00
Feed hole diameter	D2	0.5	13.00
Sprocket hole position	E	0.1	1.75
Punch hole position	F	0.1	3.50
Punch hole pitch	P	0.1	4.00
Sprocket hole pitch	P0	0.1	4.00
Embossment center	P1	0.1	2.00
Carrier thickness	T	0.02	0.21
Tape width	W	0.1	8.00
Reel width	W1	1.0	11.40

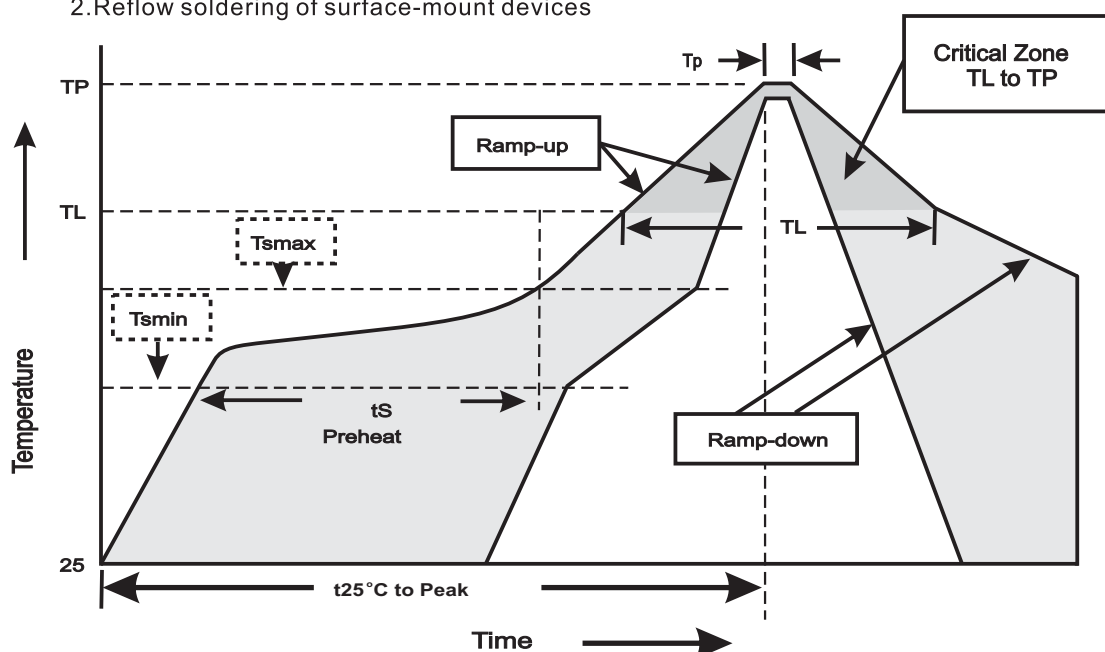
Note: Devices are packed in accordance with EIA standard RS-481-A and specifications listed above.

B5817WS-FL / B5818WS-FL / B5819WS-FL**Reel packing**

PACKAGE	REEL SIZE	REEL (pcs)	COMPONENT SPACING (m/m)	BOX (pcs)	INNER BOX (m/m)	REEL DIA, (m/m)	CARTON SIZE (m/m)	CARTON (pcs)	APPROX. GROSS WEIGHT (kg)
SOD-323FL	7"	3,000	4.0	30,000	183*123*183	178	382*257*387	240,000	8.0

Suggested thermal profiles for soldering processes

- 1.Storage environment: Temperature=5°C~40°C Humidity=55%±25%
- 2.Reflow soldering of surface-mount devices

**3.Reflow soldering**

Profile Feature	Soldering Condition
Average ramp-up rate(T _L to T _P)	<3°C/sec
Preheat -Temperature Min(T _{sm}) -Temperature Max(T _{smax}) -Time(min to max)(t _s)	150°C 200°C 60~120sec
T _{smax} to T _L -Ramp-upRate	<3°C/sec
Time maintained above: -Temperature(T _L) -Time(t _L)	217°C 60~260sec
Peak Temperature(T _P)	255°C-0/+5°C
Time within 5°C of actual Peak Temperature(t _P)	10~30sec
Ramp-down Rate	<6°C/sec
Time 25°C to Peak Temperature	<6minutes

B5817WS-FL / B5818WS-FL / B5819WS-FL**High reliability test capabilities**

Item Test	Conditions	Reference
1. Solder Resistance	at $260 \pm 5^{\circ}\text{C}$ for 10 ± 2 sec.	MIL-STD-750D METHOD-2031
2. Solderability	at $245 \pm 5^{\circ}\text{C}$ for 5 sec.	MIL-STD-202F METHOD-208
3. High Temperature Reverse Bias	$V_R = 80\%$ rate at $T_J = 125^{\circ}\text{C}$ for 168 hrs.	MIL-STD-750D METHOD-1038
4. Forward Operation Life	Rated average rectifier current at $T_A = 25^{\circ}\text{C}$ for 500hrs.	MIL-STD-750D METHOD-1027
5. Intermittent Operation Life	$T_A = 25^{\circ}\text{C}$, $I_F = I_O$ On state: power on for 5 min. off state: power off for 5 min. on and off for 500 cycles.	MIL-STD-750D METHOD-1036
6. Pressure Cooker	$15P_{SIG}$ at $T_A = 121^{\circ}\text{C}$ for 4 hrs.	JESD22-A102
7. Temperature Cycling	-55°C to $+125^{\circ}\text{C}$ dwelled for 30 min. and transferred for 5min. total 10 cycles.	MIL-STD-750D METHOD-1051
8. Forward Surge	Peak Forward Surge Current at 60Hz for 1 cycle	MIL-STD-750D METHOD-4066-2
9. Humidity	at $T_A = 85^{\circ}\text{C}$, RH=85% for 1000hrs.	MIL-STD-750D METHOD-1021
10. High Temperature Storage Life	at 175°C for 1000 hrs.	MIL-STD-750D METHOD-1031